Abstract of the Disclosure

A connective structure is formed by first depositing an insulator over a planarized surface. A trench is etched in the insulator. A barrier layer is deposited on the insulator. A seed layer is deposited on the barrier layer. The barrier layer and seed layer are selectively removed from areas of the insulator leaving an exposed seed area. A conductor is deposited on the exposed seed area. As many of these connective structures as desired may be stacked in an integrated circuit structure.

10

5

15

Express Mail mailing label number: EM2878492	29705
Date of Deposit: MARCH 1991	
I hereby certify that this paper or fee is being deposited with the United States Postal Service 'Express Mail Post Office to Addressee'	
service under 37 CFR 1.10 on the date indicated above and is addressed to the Assistant Commissioner for Patents,	4
	•
Printed Name: CHAS HAMMOND	
/ 1/2 /	